

# Hex D Flip-Flop with Common Clock and Reset



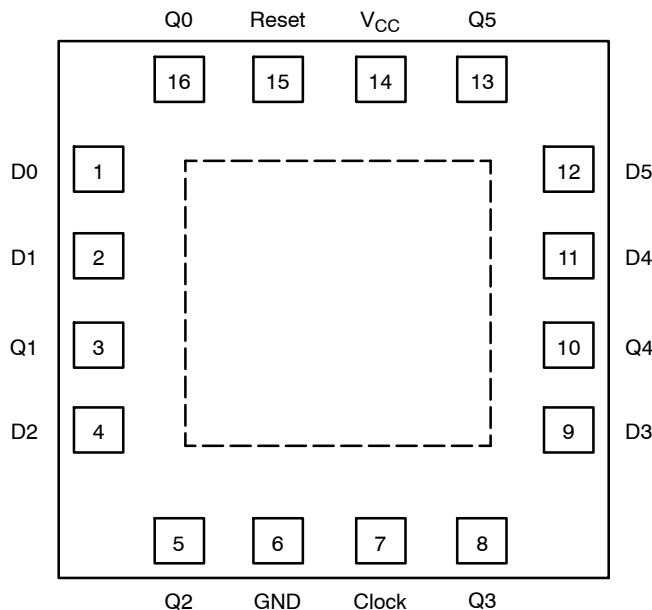
QFN-16  
MN SUFFIX  
CASE 485G

## NLSF1174

This device consists of six D flip-flops with common Clock and Reset inputs. Each flip-flop is loaded with a low-to-high transition of the Clock input. Reset is asynchronous and active low. All inputs/outputs are standard CMOS compatible.

### Features

- Output Drive Compatibility: 10 LSTTL Loads
- Outputs Directly Interface to CMOS
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0  $\mu$ A
- MSL Level 1
- Chip Complexity: 162 FET
- Pb-Free Package is Available\*

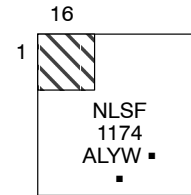


Center pad on bottom may be connected to  $V_{CC}$  of device.  
This pad must be isolated or connected to  $V_{CC}$ .

Figure 1. PIN ASSIGNMENT (Top View)

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, [SOLDERRM/D](http://www.onsemi.com/SOLDERRM/D).

### MARKING DIAGRAM



NLSF1174 = Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

### FUNCTION TABLE

Inputs			Output
Reset	Clock	D	Q
L	X	X	L
H		H	H
H		L	L
H	L	X	No Change
H		X	No Change

### ORDERING INFORMATION

Device	Package	Shipping†
NLSF1174MNR2G	QFN-16 (Pb-Free)	3000 / Tape & Reel

### DISCONTINUED (Note 1)

NLSF1174MNR2	QFN-16	3000 / Tape & Reel
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†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](http://www.onsemi.com/BRD8011/D).

1. **DISCONTINUED:** This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on [www.onsemi.com](http://www.onsemi.com).

# NLSF1174

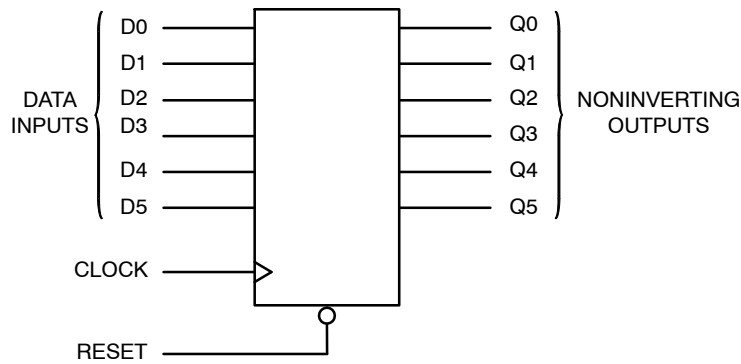


Figure 2. LOGIC DIAGRAM

## DESIGN/VALUE TABLE

Design Criteria	Value	Unit
Internal Gate Count*	40.5	ea
Internal Gate Propagation Delay	1.5	ns
Internal Gate Power Dissipation	5.0	$\mu$ W
Speed Power Product	.0075	pJ

\*Equivalent to a two-input NAND gate.

## MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
DC Supply Voltage (Referenced to GND)	$V_{CC}$	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	$V_{IN}$	-1.5 to $V_{CC} + 1.5$	V
DC Output Voltage (Referenced to GND) (Note 2)	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
DC Input Current, per Pin	$I_{IN}$	$\pm 20$	mA
DC Output Current, per Pin	$I_{OUT}$	$\pm 25$	mA
DC Supply Current, $V_{CC}$ and GND Pins	$I_{CC}$	$\pm 50$	mA
Storage Temperature Range	$T_{STG}$	-65 to +150	$^{\circ}$ C
Lead Temperature, 1 mm from Case for 10 Seconds PDIP, SOIC, TSSOP	$T_L$	260	$^{\circ}$ C
Junction Temperature Under Bias	$T_J$	+150	$^{\circ}$ C
Thermal Resistance QFN	$\theta_{JA}$	80	$^{\circ}$ C/W
Power Dissipation in Still Air at 85 $^{\circ}$ C QFN	$P_D$	800	mW
Moisture Sensitivity	MSL	Level 1	
Flammability Rating Oxygen Index: 30 to 35	$F_R$	UL 94 V-0 @ 0.125 in	
ESD Withstand Voltage Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	$V_{ESD}$	>2000 >100 >500	V
Latchup Performance Above $V_{CC}$ and Below GND at 85 $^{\circ}$ C (Note 6)	$I_{LATCHUP}$	$\pm 300$	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- $I_O$  absolute maximum rating must be observed.
- Tested to EIA/JESD22-A114-A.
- Tested to EIA/JESD22-A115-A.
- Tested to JESD22-C101-A.
- Tested to EIA/JESD78.
- For high frequency or heavy load considerations, see the **onsemi** High-Speed CMOS Data Book (DL129/D).

**RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol	Min	Max	Unit
DC Supply Voltage (Referenced to GND)	$V_{CC}$	2.0	6.0	V
DC Input Voltage, Output Voltage (Referenced to GND) (Note 8)	$V_{IN}, V_{OUT}$	0	$V_{CC}$	V
Operating Temperature, All Package Types	$T_A$	-55	+125	°C
Input Rise and Fall Time (Figure 4)	$t_r, t_f$	0	1000	ns
	$V_{CC} = 2.0\text{ V}$	0	500	
	$V_{CC} = 4.5\text{ V}$	0	500	
	$V_{CC} = 6.0\text{ V}$	0	400	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

8. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

**DC ELECTRICAL CHARACTERISTICS** (Voltages Referenced to GND)

Parameter	Test Conditions	Symbol	$V_{CC}$ V	Guaranteed Limit			Unit
				-55 °C to 25 °C	≤85 °C	≤125 °C	
Minimum High-Level Input Voltage	$V_{OUT} = 0.1\text{ V}$ or $V_{CC} - 0.1\text{ V}$ $ I_{OUT}  \leq 20\ \mu\text{A}$	$V_{IH}$	2.0	1.5	1.5	1.5	V
			4.5	3.15	3.15	3.15	
			6.0	4.2	4.2	4.2	
Maximum Low-Level Input Voltage	$V_{OUT} = 0.1\text{ V}$ or $V_{CC} - 0.1\text{ V}$ $ I_{OUT}  \leq 20\ \mu\text{A}$	$V_{IL}$	2.0	0.5	0.5	0.5	V
			4.5	1.35	1.35	1.35	
			6.0	1.8	1.8	1.8	
Minimum High-Level Output Voltage	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 20\ \mu\text{A}$	$V_{OH}$	2.0	1.9	1.9	1.9	V
			4.5	4.4	4.4	4.4	
	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 4.0\text{ mA}$ $ I_{OUT}  \leq 5.2\text{ mA}$		4.5	3.98	3.84	3.7	
			6.0	5.48	5.34	5.2	
Maximum Low-Level Output Voltage	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 20\ \mu\text{A}$	$V_{OL}$	2.0	0.1	0.1	0.1	V
			4.5	0.1	0.1	0.1	
	$V_{IN} = V_{IH}$ or $V_{IL}$ $ I_{OUT}  \leq 4.0\text{ mA}$ $ I_{OUT}  \leq 5.2\text{ mA}$		4.5	0.26	0.33	0.4	
			6.0	0.26	0.33	0.4	
Maximum Input Leakage Current	$V_{IN} = V_{CC}$ or GND	$I_{IN}$	6.0	±0.1	±1.0	±1.0	μA
Maximum Quiescent Supply Current (per Package)	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0\ \mu\text{A}$	$I_{CC}$	6.0	4.0	40	160	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

9. Information on typical parametric values, along with high frequency or heavy load considerations, can be found in the **onsemi** High-Speed CMOS Data Book (DL129/D).

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## AC ELECTRICAL CHARACTERISTICS (C<sub>L</sub> = 50 pF, Input t<sub>r</sub> = t<sub>f</sub> = 6.0 ns)

Parameter	Symbol	V <sub>CC</sub> V	Guaranteed Limit			Unit
			-55 °C to 25 °C	≤85 °C	≤125 °C	
Maximum Clock Frequency (50% Duty Cycle) (Figures 4 and 7)	f <sub>max</sub>	2.0	6.0	4.8	4.0	MHz
		4.5	30	24	20	
		6.0	35	28	24	
Maximum Propagation Delay, Clock to Q (Figures 5 and 7)	t <sub>PLH</sub> t <sub>PHL</sub>	2.0	110	140	165	ns
		4.5	22	28	33	
		6.0	19	24	28	
Maximum Propagation Delay, Reset to Q (Figures 2 and 7)	t <sub>PLH</sub> t <sub>PHL</sub>	2.0	110	140	160	ns
		4.5	21	28	32	
		6.0	19	24	27	
Maximum Output Transition Time, Any Output (Figures 4 and 7)	t <sub>TLH</sub> t <sub>THL</sub>	2.0	75	95	110	ns
		4.5	15	19	22	
		6.0	13	16	19	
Maximum Input Capacitance	C <sub>in</sub>		10	10	10	pF

Power Dissipation Capacitance, per Enabled Output (Note 11)	C <sub>PD</sub>	Typical @ 25 °C, V <sub>CC</sub> = 5.0 V		pF
		62		

10. For propagation delays with loads other than 50 pF, and information on typical parametric values, see the **onsemi** High-Speed CMOS Data Book (DL129/D).

11. Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ . For load considerations, see the **onsemi** High-Speed CMOS Data Book (DL129/D).

## TIMING REQUIREMENTS (C<sub>L</sub> = 50 pF, Input t<sub>r</sub> = t<sub>f</sub> = 6.0 ns)

Parameter	Figure	Symbol	V <sub>CC</sub> V	Guaranteed Limit						Unit
				-55 °C to 25 °C		≤85 °C		≤125 °C		
				Min	Max	Min	Max	Min	Max	
Minimum Setup Time, Data to Clock	6	t <sub>su</sub>	2.0	50		65		75		ns
			4.5	10		13		15		
			6.0	9.0		11		13		
Minimum Hold Time, Clock to Data	6	t <sub>h</sub>	2.0	5.0		5.0		5.0		ns
			4.5	5.0		5.0		5.0		
			6.0	5.0		5.0		5.0		
Minimum Recovery Time, Reset Inactive to Clock	5	t <sub>rec</sub>	2.0	5.0		5.0		5.0		ns
			4.5	5.0		5.0		5.0		
			6.0	5.0		5.0		5.0		
Minimum Pulse Width, Clock	4	t <sub>w</sub>	2.0	75		95		110		ns
			4.5	15		19		22		
			6.0	13		16		19		
Minimum Pulse Width, Reset	5	t <sub>w</sub>	2.0	75		95		110		ns
			4.5	15		19		22		
			6.0	13		16		19		
Maximum Input Rise and Fall Times	4	t <sub>r</sub> , t <sub>f</sub>	2.0		1000		1000		1000	ns
			4.5		500		500		500	
			6.0		400		400		400	

# NLSF1174

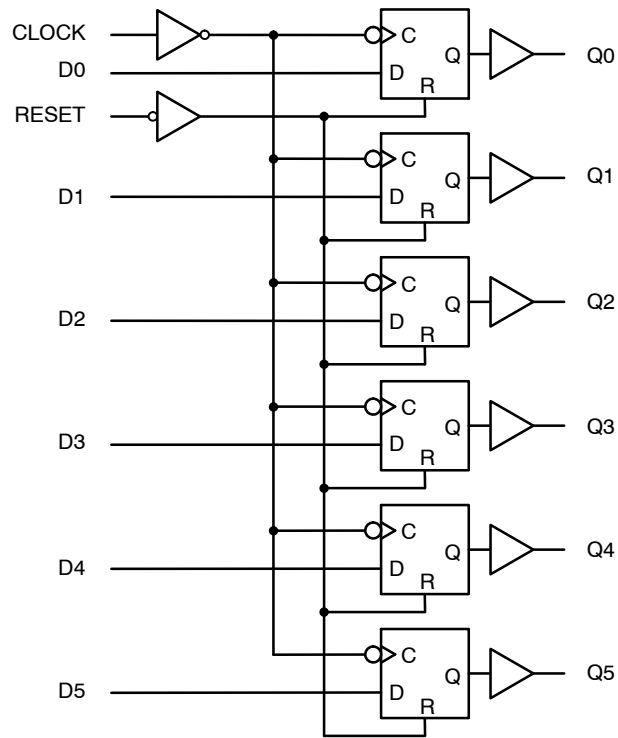


Figure 3. Expanded Logic Diagram

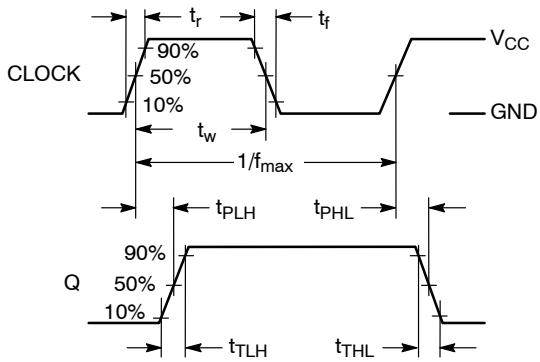


Figure 4. Switching Waveform

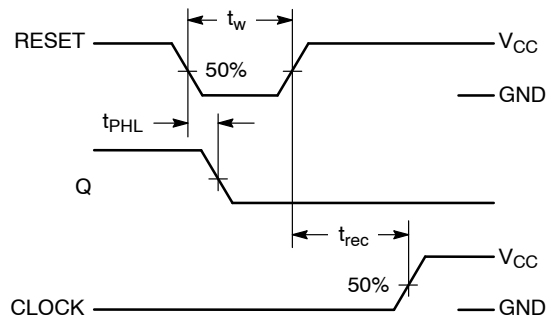


Figure 5. Switching Waveform

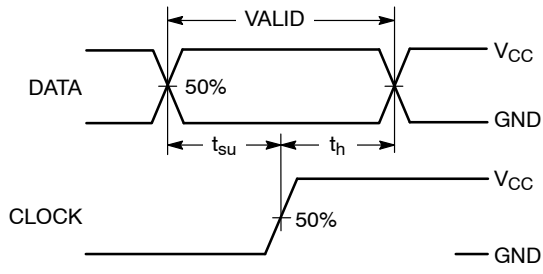
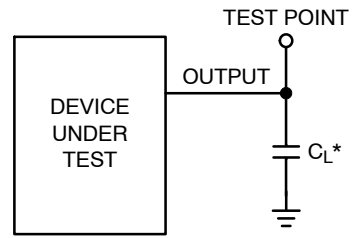


Figure 6. Switching Waveform



\*Includes all probe and jig capacitance

Figure 7. Test Circuit

**PIN1/PRODUCT ORIENTATION CARRIER TAPE**

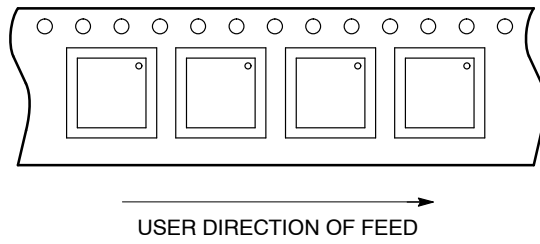


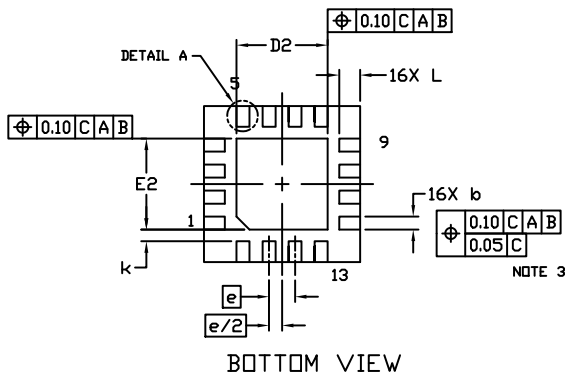
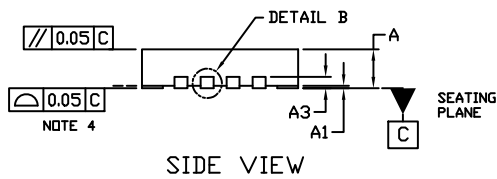
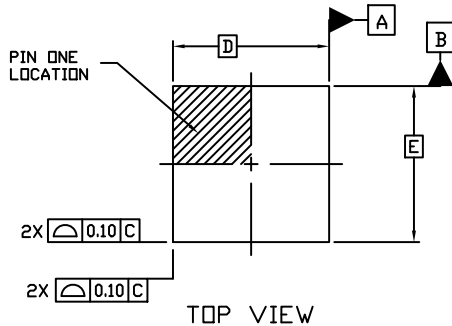
Figure 8.



1  
SCALE 2:1

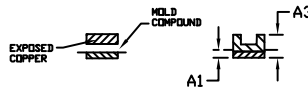
QFN16 3x3, 0.5P  
CASE 485G  
ISSUE G

DATE 08 OCT 2021

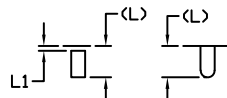


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.



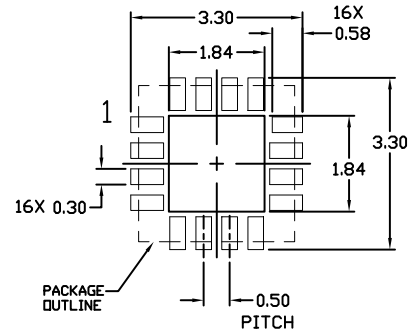
DETAIL B  
ALTERNATE CONSTRUCTIONS



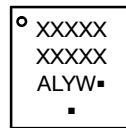
DETAIL A  
ALTERNATE TERMINAL CONSTRUCTIONS

DIM	MILLIMETERS		
	MIN.	NDM.	MAX.
A	0.80	0.90	1.00
A1	0.00	0.03	0.05
A3	0.20 REF		
b	0.18	0.24	0.30
D	3.00 BSC		
D2	1.65	1.75	1.85
E	3.00 BSC		
E2	1.65	1.75	1.85
e	0.50 BSC		
k	0.18 TYP		
L	0.30	0.40	0.50
L1	0.00	0.08	0.15

MOUNTING FOOTPRINT



GENERIC MARKING DIAGRAM\*



- XXXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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